

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Yamaguchi et al. Docket No: TI-31471  
Serial No: TBD Examiner: TBD  
Filed: Herewith Art Unit: TBD  
For: SEMICONDUCTOR DEVICE AND BUMP FORMATION METHOD

jc997 U.S. PTO  
10/087556  
03/01/02

CLAIM FOR PRIORITY FROM FOREIGN APPLICATION UNDER 35 U.S.C. §119

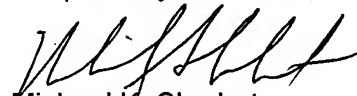
Assistant Commissioner For Patents  
Washington, DC 20231

Dear Sir:

I hereby claim foreign priority benefits under 35 U.S.C. §119(a)-(d) or (f), or 365(b) of any foreign application(s) for patent, inventor's or plant breeder's rights certificate(s), or 365(a) of any PCT International application which designated at least one country other than the United States of America, listed below and have also identified below, by checking the box, any foreign application for patent, inventor's or plant breeder's rights certificate(s), or any PCT international application having a filing date before that of the application which priority is claimed.

Prior Foreign Application Number(s)	Country	Foreign Filing Date	Priority Not Claimed	Certified Copy Attached?	
				Yes	No
2001-061,381	Japan	03/06/2001	<input type="checkbox"/>	<input type="checkbox"/>	<input checked="" type="checkbox"/>

Respectfully submitted,

  
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